## NSN 5962-01-120-1247

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-120-1247 **Body Length:** 0.808 inches **Body Width:** 0.294 inches **Body Height:** 0.204 inches **Operating Tempurature Range:** +0.0/+70.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** A/f37a-t36 fscm 22903 **Features Provided:** Hermetically sealed and monolithic and positive outputs and programmable and w/enable and 3-state output **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 6 input **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** -1.5 volts power source and 5.5 volts power source **Time Rating Per Chacteristic:** 50.00 nanoseconds propagation delay time, low to high level output and 50.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Memory Capacity:** Unknown **Test Data Document:** 22903-4014286-92 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 16 printed circuit Shelf Life: N/a **Unit Of Measure:** 

Yes - demil/mli

**Demilitarization:** 

## NSN 5962-01-120-1247

Memory Microcircuit - Page 2 of 2



Fiig:

A458a0